

Silicon Carbide Power MOSFET E-Series Automotive N-Channel Enhancement Mode

Features

- 3rd generation SiC MOSFET technology
- Optimized package with separate driver source pin
- 4.7mm of creepage distance between drain and source
- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_{rr})
- Halogen free, RoHS compliant
- Automotive Qualified (AEC-Q101) and PPAP Capable

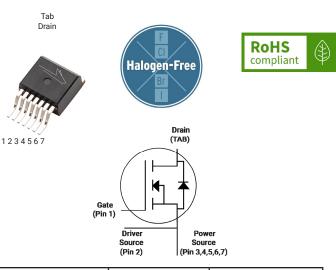
Benefits

- Reduce switching losses and minimize gate ringing
- Higher system efficiency
- Reduce cooling requirements
- Increase power density
- Increase system switching frequency

Typical Applications

- Motor Control
- EV Battery Chargers
- High Voltage DC/DC Converters

Package



Part Number	Package	Marking
E3M0021120J2	TO-263-7XL	E3M0021120J2

Maximum Ratings (T_c = 25 °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Note	
V _{DSmax}	Drain - Source Voltage		1200	V	
V _{GSmax}	Gate - Source Voltage		-8/+19	V	Note: 1
	$T_{\rm C} = 25^{\circ}{\rm C}$		114		Fig. 19
Ι _D	Continuous Drain Current, V _{GS} = 15 V	T _C = 100°C	83		Note: 2
I _{D(pulse)}	Pulsed Drain Current, Pulse width t_P limited by T_{jmax}	248	А	Fig. 22	
P _D	Power Dissipation, $T_c=25^{\circ}C$, $T_J=175^{\circ}C$		500	W	Fig. 20 Note: 2
T _J , T _{stg}	Operating Junction and Storage Temperature		-55 to +175	°C	
TL	Solder Temperature, 1.6mm (0.063") from case for 10s			°C	

Note (1): Recommended turn off / turn on gate voltage V_{gs} - 4V...0V / +15V Note (2): Verified by design

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Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions	Note	
V _{(BR)DSS}	Drain-Source Breakdown Voltage	1200		1	V	V _{GS} = 0 V, I _D = 100 μA		
	Order Three shadd) (sha wa	1.8	2.9	3.8	V	V _{DS} = V _{GS} , I _D = 17.10 mA	Fig. 11	
$V_{\text{GS(th)}}$	Gate Threshold Voltage		2.3	1	V	V _{DS} = V _{GS} , I _D = 17.10 mA, T _J = 175°C		
I _{DSS}	Zero Gate Voltage Drain Current		1	50	μA	V_{DS} = 1200 V, V_{GS} = 0 V		
I _{GSS}	Gate-Source Leakage Current		10	250	nA	V_{GS} = 15 V, V_{DS} = 0 V		
R	Drain-Source On-State Resistance		21	29	mΩ	V_{GS} = 15 V, I _D = 62.12 A	Fig. 4,	
R _{DS(on)}			35		11152	V_{GS} = 15 V, I _D = 62.12 A, T _J = 175°C	5, 6	
g fs	Transconductance		38		s	V _{DS} = 20 V, I _{DS} = 62.12 A	Fig. 7	
915			35			V _{DS} = 20 V, I _{DS} = 62.12 A, T _J = 175°C	1 ig. /	
C_{iss}	Input Capacitance		5100			V_{GS} = 0 V, V_{DS} = 0V to 1000 V		
C_{oss}	Output Capacitance		174		pF	f = 100 kHz	Fig. 17, 18	
C _{rss}	Reverse Transfer Capacitance		11	1		V _{AC} = 25 mV		
E _{oss}	Coss Stored Energy		98	1	μJ	V _{DS} = 800 V, f = 100 kHz	Fig. 16	
C _{o(er)}	Effective Output Capacitance (Energy Related)		210	1	pF		Note: 3	
C _{o(tr)}	Effective Output Capacitance (Time Related)		323	1	pF	$V_{GS} = 0 V, V_{DS} = 0 \text{ to } 800 V$		
Eon	Turn-On Switching Energy (Body Diode FWD)		1.7				Fig. 26, 28	
EOFF	Turn-Off Switching Energy (Body Diode FWD)		0.3		mJ	$R_{G(ext)} = 2.5 \Omega$, L= 39 µH, TJ = 175 °C FWD = Internal Body Diode		
t _{d(on)}	Turn-On Delay Time		15					
t,	Rise Time		34		ĺ	$V_{DD} = 800 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_D = 62.12 \text{ A},$ $R_{G(ext)} = 2.5 \Omega, L = 59 \mu\text{H}, T_J = 25^{\circ}\text{C}$	Fig. 27,	
$t_{d(off)}$	Turn-Off Delay Time		54		ns	Timing relative to V_{DS}	28	
t _f	Fall Time		13		1	Inductive load		
R _{G(int)}	Internal Gate Resistance		2.9		Ω	f = 1 MHz, V _{AC} = 25 mV		
Q_{gs}	Gate to Source Charge		60	1		V _{DS} = 800 V, V _{GS} = -4 V/15 V		
Q_{gd}	Gate to Drain Charge		45	1	nC	$V_{DS} = 600 \text{ V}, V_{GS} = -4 \text{ V} + 3 \text{ V}$ $I_D = 62.12 \text{ A}$	Fig. 12	
Qg	Total Gate Charge	l i	169	7		Per IEC60747-8-4 pg 21		

Electrical Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Note (3): $C_{o(er)}$, a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 800V $C_{o(tr)}$, a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 800V



Reverse Diode Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
N	Diada Famuard Valtaga	4.9		V	V _{gs} = -4 V, I _{sp} = 31.1 A, T _j = 25 °C	Fig. 8,	
V _{SD}	Diode Forward Voltage	4.4		V	V _{gs} = -4 V, I _{sp} = 31.1 A, T _j = 175 °C	9,10	
Is	Continuous Diode Forward Current		85	А	$V_{gS} = -4 V, T_{C} = 25^{\circ}C$		
I _{S, pulse}	Diode pulse Current		248	А	V_{gS} = -4 V, pulse width t_P limited by T_{jmax}		
t _{rr}	Reverse Recover time	16		ns			
Q _{rr}	Reverse Recovery Charge	416		nC	V _{GS} = -4 V, I _{SD} = 62.12 A, V _R = 800 V di _F /dt = 5300 A/µs, T _J = 25 °C		
I _{rrm}	Peak Reverse Recovery Current	44		А			
t _{rr}	Reverse Recover time	22		ns			
Q _{rr}	Reverse Recovery Charge	268		nC	$V_{GS} = -4 V, I_{SD} = 62.12 A, V_{R} = 800 V$ $di_{F}/dt = 2240 A/\mu s, T_{I} = 25 °C$		
I _{rrm}	Peak Reverse Recovery Current	21		A	- Francisco - Fran		

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
R _{0JC}	Thermal Resistance from Junction to Case	0.23	0.30	°C/W		Fig. 21



Typical Performance

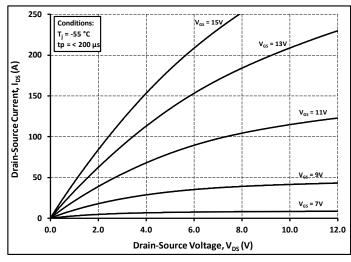
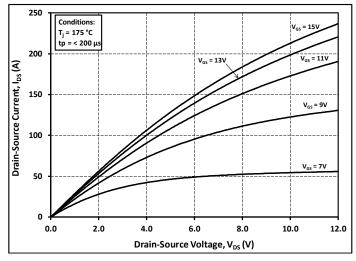
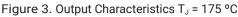
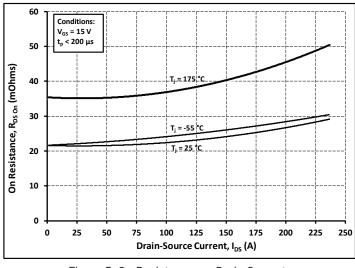
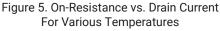


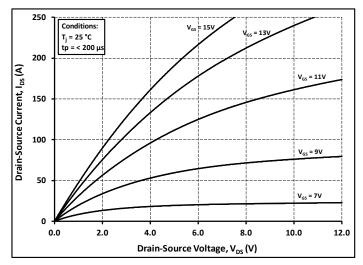
Figure 1. Output Characteristics T_J = -55 °C



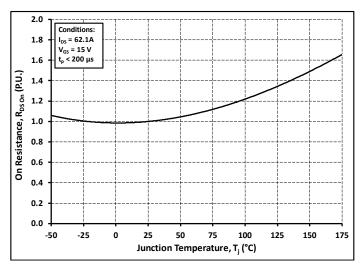




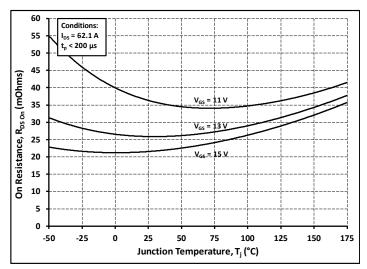














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0

-25

-50

-75

-100

-125

-150

-175

-200

0

-25

-50

-75

-100 -125

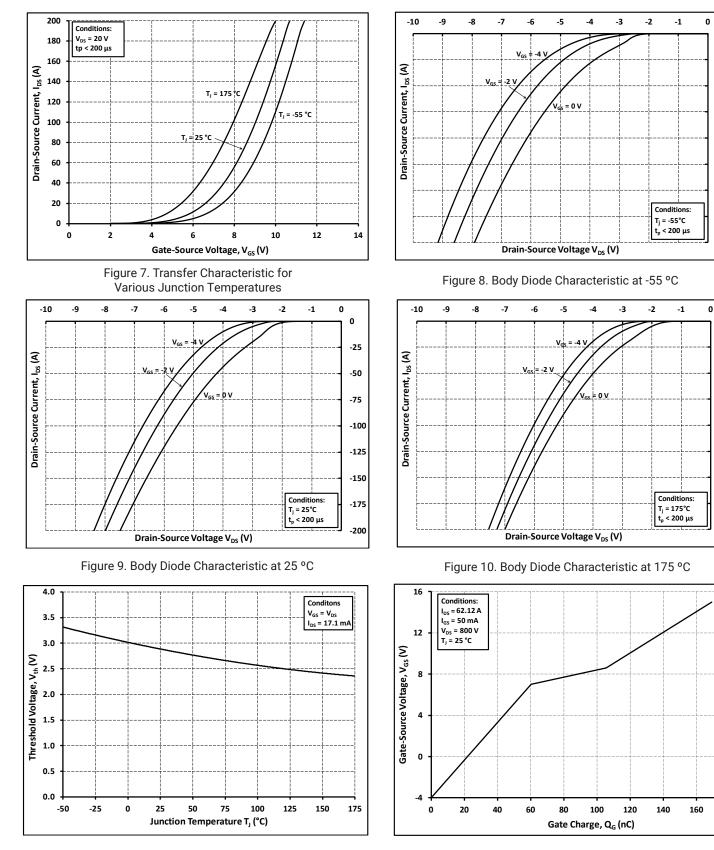
-150

-175

-200

180

Typical Performance



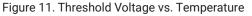


Figure 12. Gate Charge Characteristics

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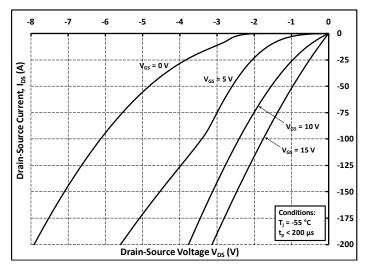


Figure 13. 3rd Quadrant Characteristic at -55 °C

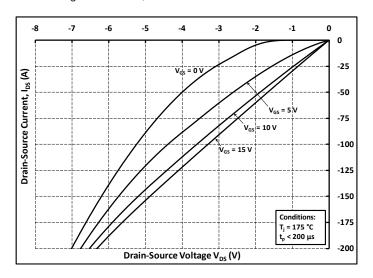
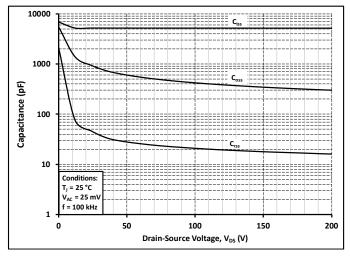
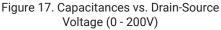


Figure 15. 3rd Quadrant Characteristic at 175 °C





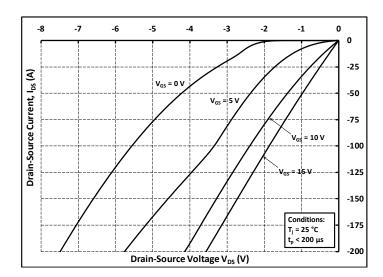


Figure 14. 3rd Quadrant Characteristic at 25 °C

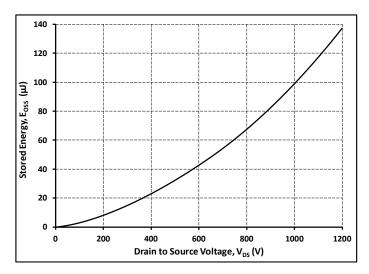


Figure 16. Output Capacitor Stored Energy

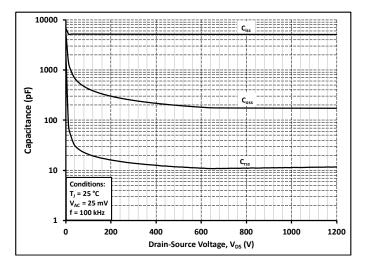
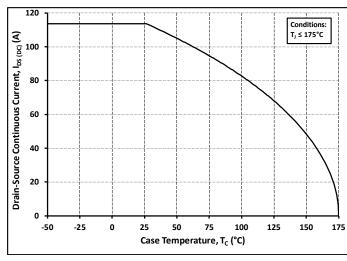


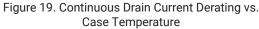
Figure 18. Capacitances vs. Drain-Source Voltage (0 - 1200V)

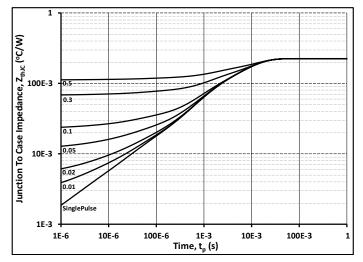
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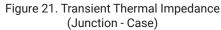
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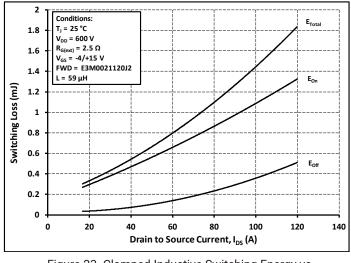
Typical Performance

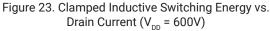


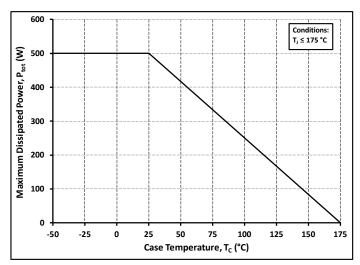




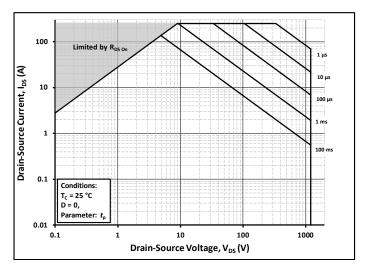


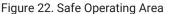


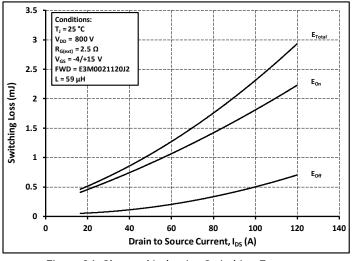


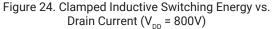












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Typical Performance

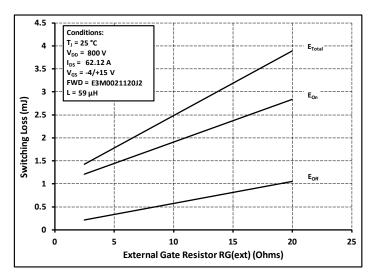


Figure 25. Clamped Inductive Switching Energy vs. $R_{G(ext)}$

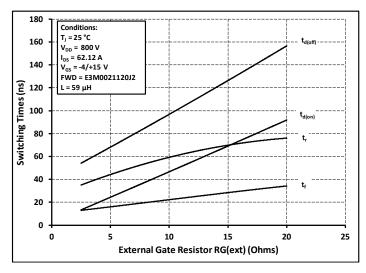


Figure 27. Switching Times vs. $R_{G(ext)}$

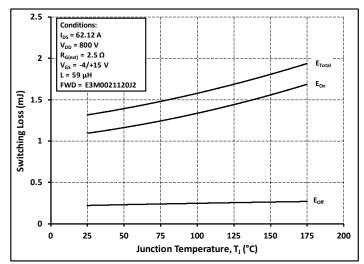


Figure 26. Clamped Inductive Switching Energy vs. Temperature

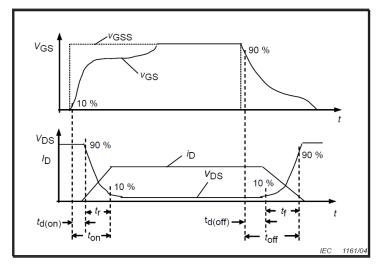
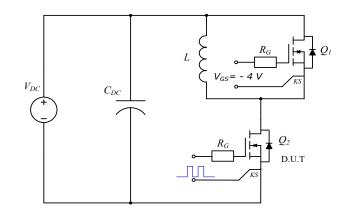
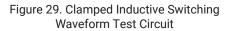


Figure 28. Switching Times Definition

Test Circuit Schematic



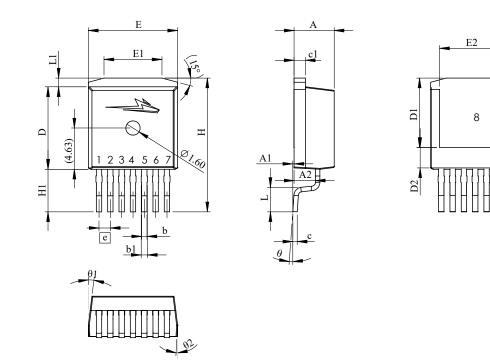




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Package Dimensions



SYMBOL	MIN (mm)	MAX (mm)		
Α	4.30	4.70		
A1	0.00	0.25		
A2	2.20	2.60		
b	0.52	0.72		
b1	0.60	0.80		
с	0.42	0.62		
c1	1.07	1.47		
D	9.05	9.45		
D1	7.58	7.98		
D2	2.05	2.45		
E	9.80	10.20		
E1	6.30	6.97		
E2	7.80	8.20		
e	1.27 BSC			
Н	14.87	15.27		
H1	4.55	4.95		
L	2.48	2.88		
L1	0.87	1.27		
θ	0°	8°		
θ1	4°	10°		
θ2	0°	6°		

1	GATE
2	KELVIN
3	
4	
5	SOURCE
6	
7	
8	DRAIN

NOTE

1. ALL METAL SURFACES ARE TIN PLATED (MATTE), EXCEPT AREA OF CUT.

2. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.

3. ALL DIMENSIONS ARE LISTED IN MILLIMETERS. ANGLES ARE IN DEGREES.

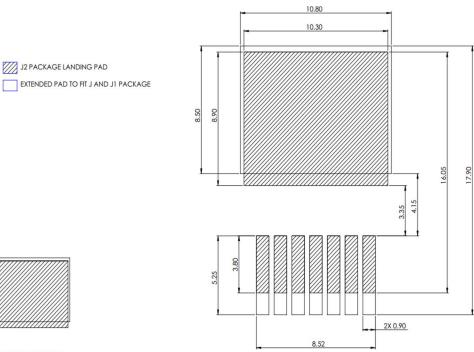
4. PACKAGE BURR FLASH SIZE (0.5 mm) IS NOT INCLUDED IN THE DIMENSIONS

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Recommended Solder Pad Layout

All dimensions in mm





NOTE: J2 LANDING PAD WAS DESIGNED FOLLOWING IPC 7351 GUIDELINES



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Revision history

Document Version	Date of release	Descriptiion of changes
1.0	December 2023	Initial release
2	December- 2023	Operating Temp Corrected
3	January - 2025	Legal Disclaimer Updated

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